

**Product data sheet** 

## 1. General description

Dual P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 2. Features and benefits

- Low threshold voltage
- Leadless ultra small and ultra thin SMD plastic package 1.1 x 1.0 x 0.37 mm
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

## 3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor								
$V_{DS}$	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-30	V	
$V_{GS}$	gate-source voltage			-8	-	8	٧	
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-	-410	mA	
Static characteristics (per transistor)								
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = -4.5 V; $I_D$ = -410 mA; $T_j$ = 25 °C		-	1.2	1.4	Ω	

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.



# 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	S1	source TR1	h / 1 c	D1 D2	
2	G1	gate TR1	$\begin{bmatrix} 1 \\ 7 \end{bmatrix} \begin{bmatrix} 6 \\ \end{bmatrix}$		
3	D2	drain TR2	2 5	G1 $G2$ $G2$	
4	S2	source TR2	3 8 4  Transparent top view	3 8 4	
5	G2	gate TR2			
6	D1	drain TR1			S1 S2 017aaa260
7	D1	drain TR1	DFN1010B-6 (SOT1216)		
8	D2	drain TR2			

# 6. Ordering information

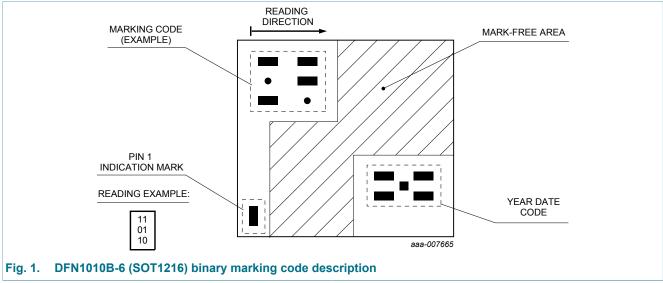
Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PMDXB1200UPE	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216		

# 7. Marking

Table 4. Marking codes

Type number	Marking code
PMDXB1200UPE	11 10 00



PMDXB1200UPE

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# 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transis	tor					
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-30	V
$V_{GS}$	gate-source voltage			-8	8	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C	[1]	-	-410	mA
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	-260	mA
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-1.7	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	285	mW
			[1]	-	410	mW
		T <sub>sp</sub> = 25 °C		-	4030	mW
Source-dra	in diode					
Is	source current	T <sub>amb</sub> = 25 °C	[1]	-	-410	mA
Per device						_
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>

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<sup>[2]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

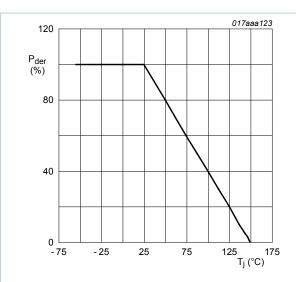


Fig. 2. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

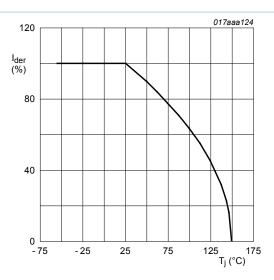


Fig. 3. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

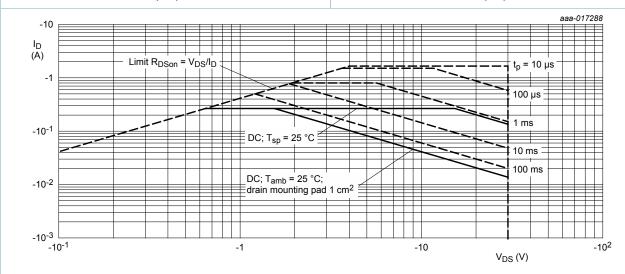


Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

### 9. Thermal characteristics

Table 6. Thermal characteristics

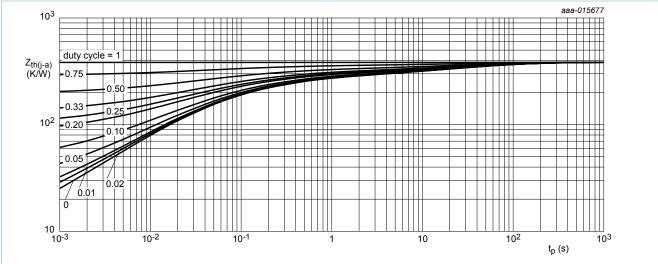
Ol	D	0		B.41	T	N/I	1124
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
R <sub>th(j-a)</sub>	thermal resistance	in free air	[1]	-	380	440	K/W
	from junction to ambient		[2]	-	275	305	K/W

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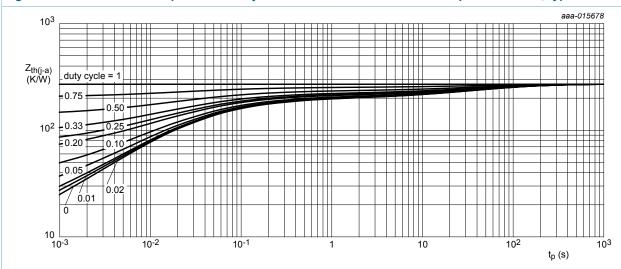
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		-	27	31	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.



FR4 PCB, standard footprint

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for drain 1 cm<sup>2</sup>

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 10. Characteristics

Table 7 Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics (per transistor)		'			
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D$ = -250 $\mu$ A; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-30	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25 °C$	-0.45	-0.7	-0.95	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = -30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	5	μA
		V <sub>GS</sub> = -8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-5	μA
		V <sub>GS</sub> = 4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
		V <sub>GS</sub> = -4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μA
		$V_{GS} = 2.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	100	nA
		V <sub>GS</sub> = -2.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-100	nA
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = -4.5 V; $I_D$ = -410 mA; $T_j$ = 25 °C	-	1.2	1.4	Ω
		$V_{GS}$ = -4.5 V; $I_D$ = -410 mA; $T_j$ = 150 °C	-	2	2.4	Ω
		$V_{GS}$ = -2.5 V; $I_D$ = -320 mA; $T_j$ = 25 °C	-	1.7	2.3	Ω
		$V_{GS}$ = -1.8 V; $I_D$ = -80 mA; $T_j$ = 25 °C	-	2.1	3.1	Ω
		$V_{GS}$ = -1.5 V; $I_D$ = -10 mA; $T_j$ = 25 °C	-	3	5.1	Ω
9fs	forward transconductance	$V_{DS}$ = -10 V; $I_{D}$ = -410 mA; $T_{j}$ = 25 °C	-	820	-	mS
Dynamic c	haracteristics (per transist	or)				
$Q_{G(tot)}$	total gate charge	$V_{DS} = -15 \text{ V}; I_D = -410 \text{ mA};$	-	0.7	1.2	nC
$Q_{GS}$	gate-source charge	$V_{GS} = -4.5 \text{ V}; T_j = 25 \text{ °C}$	-	0.17	-	nC
$Q_{GD}$	gate-drain charge		-	0.16	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS} = -15 \text{ V}; f = 1 \text{ MHz}; V_{GS} = 0 \text{ V};$	-	43.2	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	5.9	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	4.2	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = -15 V; I <sub>D</sub> = -410 mA;	-	3	-	ns
t <sub>r</sub>	rise time	$V_{GS} = -4.5 \text{ V}; R_{G(ext)} = 6 \Omega; T_j = 25 \text{ °C}$	-	4	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	14	-	ns
t <sub>f</sub>	fall time		-	5	-	ns
Source-dra	nin diode (per transistor)		ı			
$V_{SD}$	source-drain voltage	$I_S$ = -410 mA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-0.95	-1.2	V

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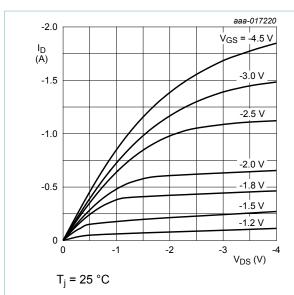
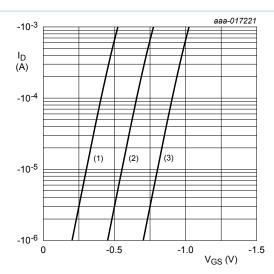


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values



 $V_{DS} = -5 V$ 

T<sub>j</sub> = 25 °C

(1) minimum values

(2) typical values

(3) maximum values

Fig. 8. Sub-threshold drain current as a function of gate-source voltage

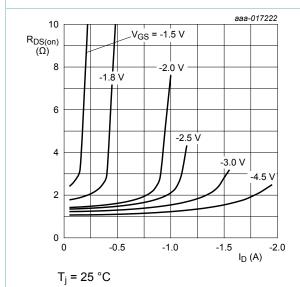


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

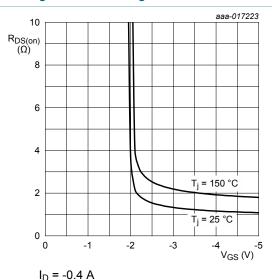


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

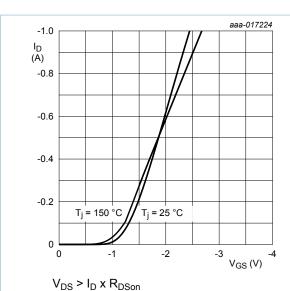


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

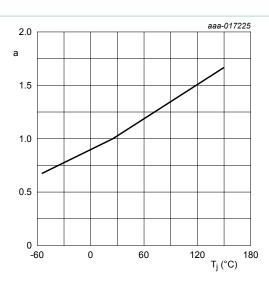
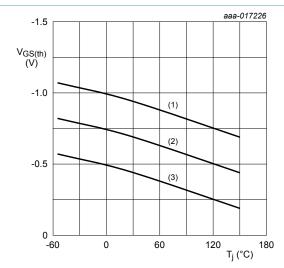


Fig. 12. Normalized drain-source on-state resistance as a function of ambient temperature; typical values

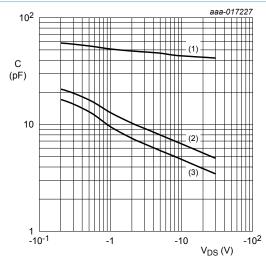
$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$



 $I_D = -250 \mu A; V_{DS} = V_{GS}$ 

- (1) maximum values
- (2) typical values
- (3) minimum values

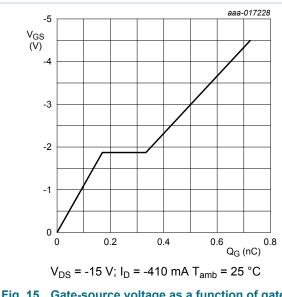
Fig. 13. Gate-source threshold voltage as a function of junction temperature



f = 1 MHz; V<sub>GS</sub> = 0 V

- (1) C<sub>iss</sub>
- (2) C<sub>oss</sub>
- (3)  $C_{rss}$

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



V<sub>GS</sub>(pl)
V<sub>GS</sub>(th)
V<sub>GS</sub>
Q<sub>GS1</sub> Q<sub>GS2</sub>
Q<sub>G</sub>(tot)
017aaa137

Fig. 16. Gate charge waveform definitions

Fig. 15. Gate-source voltage as a function of gate charge; typical values

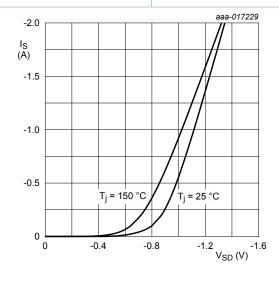
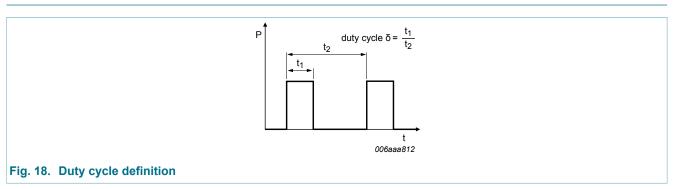


Fig. 17. Source current as a function of source-drain voltage; typical values

## 11. Test information

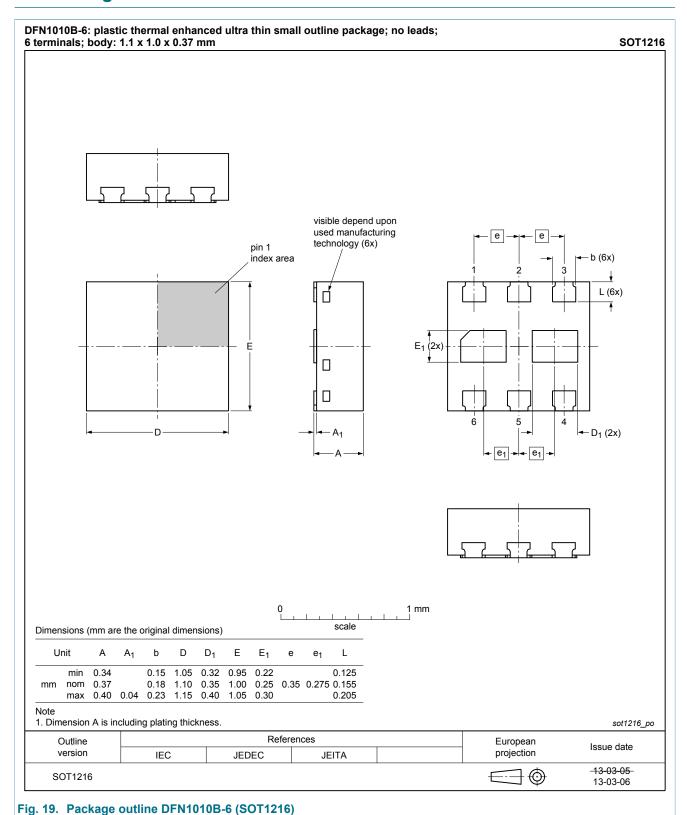
 $V_{GS} = 0 V$ 



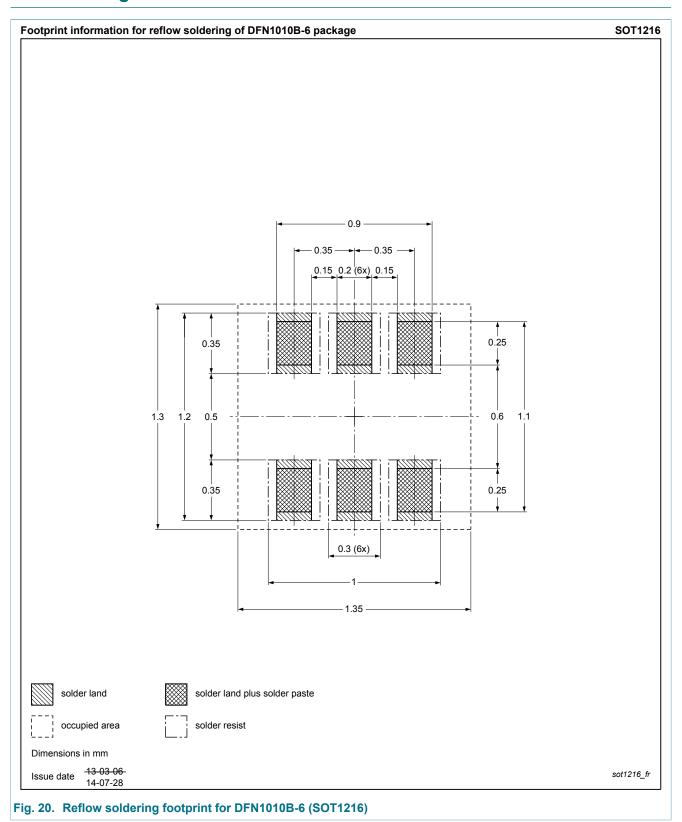
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## 12. Package outline



## 13. Soldering



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# 14. Revision history

### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMDXB1200UPE v.1	20150325	Product data sheet	-	-

## 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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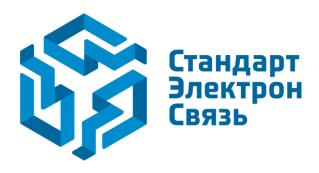
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